

Vishay Semiconductors

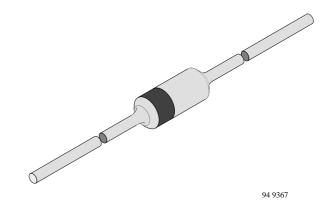
Small Signal Schottky Barrier Diodes

Features

- Integrated protection ring against static discharge
- Low capacitance
- Low leakage current
- Low forward voltage drop



HF-Detector
Protection circuit
Diode for low currents with a low supply voltage
Small battery charger
Power supplies
DC / DC converter for notebooks



Order Instruction

Туре	Type Differentiation	Ordering Code	Remarks	
SD101A	V _R =60 V, V _F @I _F 1mA max. 0.41 V	SD101A-TAP	Ammopack	
		SD101A-TR	Tape and Reel	
SD101B	V _R =50 V, V _F @I _F 1mA max. 0.4 V	SD101B-TAP	Ammopack	
		SD101B-TR	Tape and Reel	
SD101C	V _R =40 V, V _F @I _F 1mA max. 0.39 V	SD101C-TAP	Ammopack	
		SD101C-TR	Tape and Reel	

Absolute Maximum Ratings

 $T_i = 25^{\circ}C$

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Parameter	Test Conditions	Туре	Symbol	Value	Unit	
		SD101A	V_R	V _R 60		
Reverse voltage		SD101B	SD101B V _R		V	
		SD101C	V_{R}	40	V	
Peak forward surge current	t _p =10μs		I _{FSM}	2	Α	
Repetitive peak forward current	•		I _{FRM}	150	mA	
Forward current			I _F	30	mA	
Junction temperature			Tį	125	°C	
Storage temperature range			T _{sta}	<i>−</i> 65+150	°C	

Maximum Thermal Resistance

 $T_i = 25^{\circ}C$

Parameter	Test Conditions	Symbol	Value	Unit
Junction ambient	on PC board 50 mmx50 mmx1.6 mm	R _{thJA}	320	K/W

Document Number 85629

Rev. 1, 18-Jul-00

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1 (4)

SD101A-SD101C

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Electrical Characteristics

 $T_i = 25^{\circ}C$

Parameter	Test Conditions	Type	Symbol	Min	Тур	Max	Unit
Reverse Breakdown Voltage	I _R =10μA	SD101A	V _{(BR)R}	60			V
		SD101B	V _{(BR)R}	50			V
		SD101C	V _{(BR)R}	40			V
Leakage current	V _R = 50 V	SD101A	I _R			200	nA
	V _R = 40 V	SD101B	I _R			200	nA
	V _R = 30 V	SD101C	I _R			200	nA
Forward voltage drop	I _F =1mA	SD101A	V_{F}			0.41	V
		SD101B	V_{F}			0.4	V
		SD101C	V_{F}			0.39	V
	I _F =15mA	SD101A	V _F			1	V
		SD101B	V _F			0.95	V
		SD101C	V _F			0.9	V
Diode capacitance	V _R = 0 V, f= 1MHz	SD101A	C _D			2.0	pF
		SD101B	C _D			2.1	pF
		SD101C	C _D	·		2.2	pF

Characteristics $(T_j = 25^{\circ}C \text{ unless otherwise specified})$

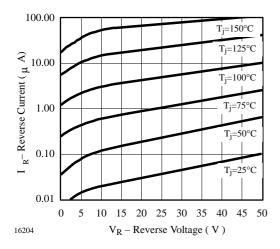


Figure 1. Reverse Current vs. Reverse Voltage

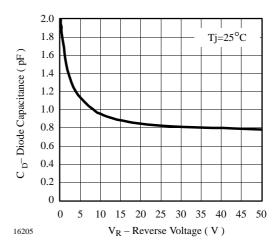


Figure 2. Diode Capacitance vs. Reverse Voltage





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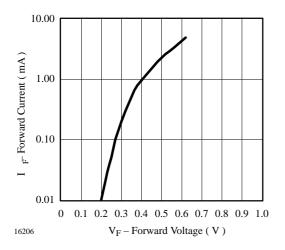
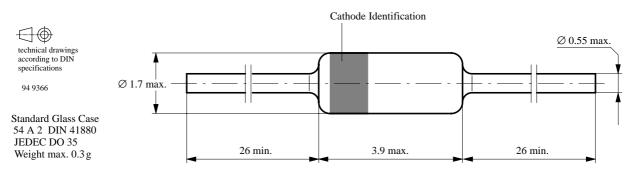


Figure 3. Forward Current vs. Forward Voltage

Dimensions in mm



SD101A-SD101C

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Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice. Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay-Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay-Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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